

RAMAKRISHNA MISSION VIDYAMANDIRA

(Residential Autonomous College affiliated to University of Calcutta)

B.A./B.Sc. SIXTH SEMESTER EXAMINATION, MAY 2017

THIRD YEAR [BATCH 2014-17]

PHYSICS (Honours)

Paper : VIII

Date : 11/05/2017

Time : 11 am – 1 pm

Full Marks : 50

Answer any five questions :

[5×10]

1. a) Explain the idea of lattice and basis for describing crystal structure. What is a Bravais lattice?
Can a honeycomb structure be considered as a Bravais lattice? [2+1+1]
b) Are the planes (010) and (020) identical? Explain. [2]
c) An element is cubic with lattice constant 4.28\AA and with two of its atoms in the unit cube at (0,0,0) and $(\frac{1}{2}, \frac{1}{2}, \frac{1}{2})$. How many nearest neighbours does each atom have in this element and how far away are they. Also find the atomic packing factor of this lattice. [1+2+1]
2. a) Considering suitable set of primitive vectors, show that the reciprocal lattice corresponding to a BCC lattice is a FCC lattice in reciprocal space. [2]
b) Starting from Ewald sphere, prove the following form of Bragg's law $2\vec{K} \cdot \vec{G} + G^2 = 0$. where \vec{K} is the wave vector of the incident x-ray and \vec{G} is the reciprocal lattice vector. [3]
c) On an X-ray powder photograph of a cubic substance with Cu- K_α radiation ($\lambda = 1.54\text{\AA}$), lines are observed at the following Bragg angles (θ in degrees); $12.3, 14.1, 20.1, 24.1, 25.1, 29.3$ and 32.2 . Identify the crystal structure and assign Miller indices to the lines. Also calculate the unit cell dimension. [4+1]
3. a) Find the relation between the frequency of vibration and wave vector \vec{K} in a linear monatomic lattice. Using this relation, deduce the expression for density of vibrational modes of the same lattice. [4+3]
b) Using Born theory calculate the lattice energy of ionic crystal. [3]
4. a) What is the density of electronic state? How does the density of electronic state relate with the energy of electron in three dimensional metal. [1+3]
b) Show that paramagnetic susceptibility due to free electrons is independent of temperature. [4]
c) The lattice constant of copper is 3.6\AA . Calculate the number of electrons per unit volume and Fermi velocity. [2]
5. a) Draw E-K diagram for free electron and electron in a solid. [1]
b) What is the physical significance of effective mass of a carrier in a periodic lattice? [2]
c) Sketch the distribution of space charge density and electric field across a p-n junction diode where p-side is lightly doped than n-side ($N_a < N_d$). [3]
d) Consider a silicon n-p-n transistor junction of $V_{eb} = 0.814\text{eV}$ and $V_{cb} = 0.635\text{eV}$ at $T = 300\text{K}$ with doping concentrations of 10^{18}cm^{-3} , 10^{16}cm^{-3} and 10^{15}cm^{-3} in E, B and C region respectively. Calculate the emitter-base space charge width W_{EB} , and base-collector space charge width W_{BC} . [$\epsilon_r = 11$ and $\epsilon_0 = 8.85 \times 10^{-14}\text{Fcm}^{-1}$]. [4]
6. a) Find the expression for the local field that is responsible for polarizing atoms of a solid dielectric of cubic symmetry. [5]
b) Give Weiss theory of spontaneous magnetization and discuss its temperature dependence. [5]

7. a) What do you mean by carrier injection in a p-n junction diode? Under low-level injection approximation find the carrier injection at the edges of the p-n junction. [1+3]
- b) Derive the London equations for superconductivity and discuss the results. [4]
- c) Consider a silicon p-n junction at $T = 300\text{K}$ with doping concentrations of $N_a = 10^{16}\text{cm}^{-3}$ and $N_d = 10^{15}\text{cm}^{-3}$. Calculate the built-in potential barrier in a p-n junction. [2]
8. a) What is Bloch theorem? Prove the Bloch theorem. [1+4]
- b) Kroning-Penny model gives a simplified solution of the form $P \frac{\sin \alpha a}{\alpha a} + \cos \alpha a = \cos Ka$, where the symbols have their usual significance. Discuss the formation of energy band and influence of P on the energy band. [5]

————— × —————